NSN 5962-01-310-3160

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View Online at https://aerobasegroup.com/nsn/5962-01-310-3160

Overall Length:

- 1.420 inches
- **Overall Height:**
- 0.455 inches

Overall Width:

0.620 inches

Body Length:

1.420 inches

Body Width:

0.604 inches

Body Height:

0.280 inches

Maximum Power Dissipation Rating:

135.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

1430-01-286-1314 guided missle

Features Provided:

Burn in and high performance and high speed and low power and asynchronous and 3-state output

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Input Circuit Pattern:

24 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

Memory Device Type:

Rom

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

28 printed circuit

Shelf Life:

N/a

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Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A458a0

